



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Turner, et al.

Attorney Docket No.: NOVLP074/NVLS-000414

Application No.: 09/998,993

Examiner: Maldonado, Julio J.

Filed: November 15, 2001

Group: 2823

Title: PHOSPHOROUS-DOPED SILICON
DIOXIDE PROCESS TO CUSTOMIZE
CONTACT ETCH PROFILES

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first-class mail on April 18, 2006 in an envelope addressed to the Commissioner for Patents, P.O. Box 1450 Alexandria, VA 22313-1450.

Signed: _____

Tara Hayden

**SEPARATE LETTER TO THE OFFICIAL DRAFTSMAN
REQUESTING ENTERING OF FORMAL DRAWINGS
(MPEP 608.02(p))**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed are substitute (formal) drawings for the above-identified patent application. If the Draftsman has any question concerning these drawings, he or she is respectfully requested to contact the undersigned.

Respectfully submitted,
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